

## UNIVERSITI TUN HUSSEIN ONN MALAYSIA

## FINAL EXAMINATION SEMESTER II SESSION 2023/2024

COURSE NAME

ANALOG ELECTRONICS

COURSE CODE

BEV 10503

PROGRAMME CODE

BEV

**EXAMINATION DATE** 

JULY 2024

**DURATION** 

3 HOURS

INSTRUCTIONS

1. ANSWER ALL QUESTIONS

2. THIS FINAL EXAMINATION IS

CONDUCTED VIA

☐ Open book ☐ Closed book

3. STUDENTS ARE **PROHIBITED** TO CONSULT THEIR OWN MATERIAL OR ANY EXTERNAL RESOURCES DURING THE EXAMINATION

CONDUCTED VIA CLOSED BOOK

THIS QUESTION PAPER CONSISTS OF FIVE (5) PAGES

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Q1 (a) Differentiate between a diode and a Zener diode.

(2 marks)

(b) Describe the difference between conductor, isolator and semiconductor.

(3 marks)

(c) Explain the majority and minority carriers in n-type and p-type semiconductors.

(2 marks)

(d) Describe the resistance levels of a diode in term of its type, equation, special characteristics and graphical determination.

(6 marks)

(e) Calculate the maximum and minimum values of input voltage  $V_i$  for the Zener diode in **Figure Q1.(e)** to maintain in the "on" state dan sketch a graph of  $V_L$  vs  $V_i$ .

(9 marks)

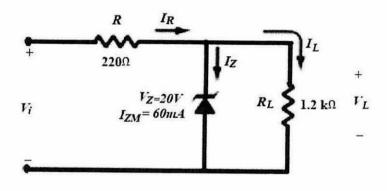


Figure Q1.(e)

(f) Describe the models of diode equivalent circuit in term of its type, conditions, equivalent model and characteristics.

(3) marks)

Q2 (a) Define the transistor construction.

(2 marks)

(b) Explain the active region, the cutoff region and the saturation region of a bipolar junction transistor in a common-base configuration.

(3 marks)

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(c) Analyse the values of  $I_{C_Q}$  and  $V_{CE_Q}$  for the voltage divider configuration of a transistor circuit in **Figure Q2.(c)** using an exact analysis and an approximate analysis.

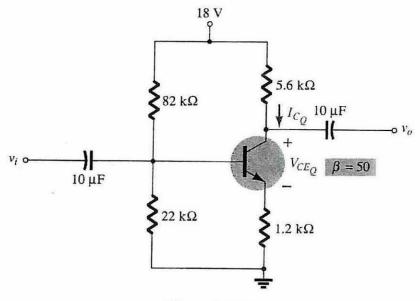


Figure Q2.(c)

(20 marks)

Q3 (a) Draw the symbols of n-channel and p-channel enhancement-type MOSFETs.

(2 marks)

(b) Describe the field-effect transistor (FET).

(1 mark)

(c) Draw the junction field-effect transistor (JFET) symbols for n-channel and p-channel.

(2 marks)

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(d) Analyse the value of  $V_{GSQ}$ ,  $I_{DQ}$ ,  $V_{DS}$ ,  $V_D$ ,  $V_G$  and  $V_S$  the transistor circuit in **Figure** Q3.(d) using mathematical approach and graphical approach.

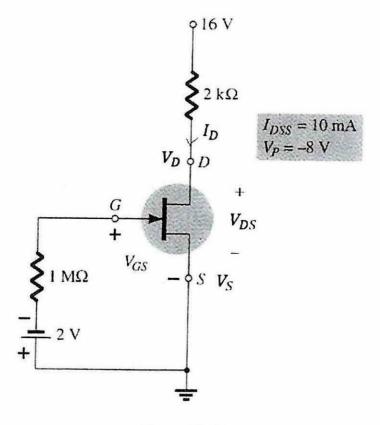


Figure Q3.(d)

(20 marks)

Q4 (a) Differentiate the power amplifier classes based on its operating cycle and power efficiency.

(5 marks)

(b) Explain in brief the FIVE (5) characteristics of power amplifier.

(5 marks)

(c) Calculate the input power, output power, and efficiency of the amplifier circuit in Figure Q4.(c) based on a base current of 10 mA peak.

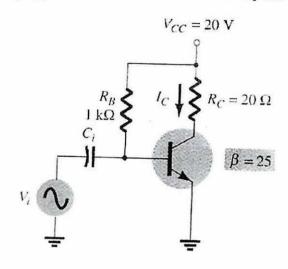


Figure Q4.(c)

(15 marks)

- END OF QUESTIONS -

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